## ECE 320 - Final Exam - Name

Spring 2020. Due Friday, March 27th, midnight
Individual Effort. Matlab, CircuitLab, and Calculators Permitted

No Aid Given, Received, or Observed: (please sign if possible): $\qquad$

1) The VI characteristics for a diode are shown on the graph below.

- Draw the load line for the circuit shown to the left, and
- Determine the operating point (Vd, Id)

| Load Line | Vd | Id |
| :---: | :---: | :---: |
| show on graph |  |  |


2) Assume ideal silicon diodes. Determine the currents and voltages for the following diode circuit.

| I1 | I2 | I3 | I4 | V1 | V2 |
| :--- | :--- | :--- | :--- | :--- | :--- |
|  |  |  |  |  |  |
|  |  |  |  |  |  |


3) AC to DC Converter: Calculate the voltages at V1 and V2 (both DC and AC).

- Assume ideal silicon diodes $(\mathrm{Vf}=0.7 \mathrm{~V})$.
- Note: your answers should be slightly different from problem \#4

| V1 |  | V2 |  |
| :---: | :---: | :---: | :---: |
| DC | AC (V1pp) | DC | AC (V2pp) |
|  |  |  |  |


4) Design a Schmitt Trigger which

- Outputs +10 V when the temperature goes above 8C,
- Outputs 0 V when the temperature drops below 4C, and
- No change for $4 \mathrm{C}<\mathrm{T}<8 \mathrm{C}$

Assume you are using a thermistor with a temperature - resistance relationship of

$$
R=1000 \cdot \exp \left(\frac{3905}{T}-\frac{3905}{298}\right) \Omega
$$

where T is the temperature in degrees Kelvin ( $\mathrm{C}+273$ ).

5) Transistors and Load Lines

Determine the following for the following transsitor circuit

| Beta | Load Line | Operating Point for |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | a) Vin $=0 \mathrm{~V}$ | b) Vin $=5 \mathrm{~V}$ | c) Vin $=10 \mathrm{~V}$ |
|  | show on graph | show on graph | show on graph | show on graph |
|  |  |  |  |  |


6) Transistor Switch. Determine Rc and Rb so that you can turn on and off a white LED at 3A. Assume

- Vf=3.0V @4A for the LED
- The transistor has a gain of 300
- $\quad$ Vbe $=0.7 \mathrm{~V}$, Vce(sat) $=0.2 \mathrm{~V}$
- Vin is capable of driving currents up to 10 mA

| Min value of Rb | Max value of Rb | Rc |
| :---: | :---: | :---: |
|  |  |  |


7) Determine the voltages for the following DTL gate. Assume ideal silicon diodes $(\mathrm{Vf}=0.7 \mathrm{~V})$ and transistors:
$\mathrm{Vbe}=0.7 \mathrm{~V}$

- Vce(sat) $=0.2 \mathrm{~V}$
- $\beta=100$

| V1 | I2 | V3 | I4 | V5 |
| :--- | :--- | :--- | :--- | :--- |
|  |  |  |  |  |
|  |  |  |  |  |


8) The characteristics for a MOSFET are

- Part: IRFD-3-\{BF
- Current - Continuous Drain (Id) @ $25^{\circ} \mathrm{C} 2.4 \mathrm{~A}$ (Tc)
- Rds On (Max) @ Id, Vgs 100mOhm @ 1.4A, 10V
- Vgs(th) (Max) @ Id 4V @ 250 $\mu \mathrm{A}$

Determine the transconductance gain, kn, Vds, and Ids for the following MOSFET circuit

| kn (A/V^2) | Vds (Volts) | Ids (mA) | Rds |
| :---: | :---: | :---: | :---: |
|  |  |  |  |



Bonus! What does CircuitLab predict the voltage at V2 is for problem \#3?

